



Reliability of PV modules and long-term performance prediction

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Two neighboring institutions





- Fundamental research
- Advanced devices

:: CSeM

- CSEM PV-Center founded in 2013
- Technology transfer center for PV
- Applied research, industrial mandates



Different missions but strong collaboration and complementary competences





Modules activities



Module reliability

- Module reliability testing and modeling
- Module components and materials accelerated reliability testing
- Module testing tools (encapsulation quality and reliability) development
- Participation in work groups for PV standards development



Modules & system integration

- New PV module encapsulation materials and interconnection techniques
- Novel encapsulation process development
- Innovative module design
- Architectural projects with PV

System

- Integration to variable grid conditions
- Batteries interfacing to PV





PV module: a multi-layer system...







...with lots of impacts & interactions







Aim: predict the module lifetime and long-term performance for a given set of conditions

- Method: build a model based on
 - A failure mode and effects analysis based on literature and field data (!)
 - Dedicated sets of *accelerated life tests* (ALTs) to reproduce predominant failure modes as a function of:
 - Climate where the module operates
 - Stand alone installation vs BIPV
 - Technology specificities (interconnects,..)
 - In literature, most authors consider one failure at a time with an Arrhenius type behavior, sometimes extended to take into account irradiance and/or humidity

Challenge here is to be able to predict impacts of **inter-related failure mechanisms** on lifetime and performance !





Examples of ALT



 Clear necessity to define qualification test beyond IEC 61215 to evaluate long-term performance as a function of climate





- Problematics of moisture ingress:
 - Delamination (mechanical stability loss, optical loss, water accumulation, ...)
 - Corrosion (R_s increase, could accelerate EVA yellowing, ...)
 - Enhanced probability of PID (due to reduced volume resistivity of encapsulants)
 - Encapsulant degradation (in combination with heat and UV)



- Different techniques can be used to minor and study water ingress:
 - Permeation WVTR Mocon, Fourier Transform Infrared Spectroscopy (FTIR),..
 - Humidity sensor





- Acquire input material properties WVTR data treatment:
- WVTR characterization of different commercial backsheets (BS) and EVAs formulations measured at various temperatures (30°C, 40°C, 50°C)



 $C_{\rm s}$ saturation concentration, l film thickness, t time

$$D(T) = D(T_{ref})e^{\frac{-E_a}{R}\left(\frac{1}{T} - \frac{1}{T_{ref}}\right)}$$





- 2D FEM modeling geometry
 - A model was built in COMSOL to solve Fick's Second Law of diffusion:

$$\frac{\partial c(\vec{x},t)}{\partial t} - div \left(D \cdot \overrightarrow{grad} c(\vec{x},t) \right) = 0$$

• Boundary Conditions (Henry's law): $c_{surf}(T, RH) = S(T) \cdot p_{H_2O}(T, RH)$







Three climatic conditions



• The module temperature was estimated using King's model: $T_{mod} = T_{amb} + E \cdot e^{-a-b \cdot v}$ with an open-rack mounting configuration







- As expected the moisture ingress is the fastest in tropical climate, with clear seasonal variations, particularly at the edge
- In the cool and humid environment, saturation is reached after 10 years at edge, very slow ingress at back of the cells
- In the desert climate saturation at edge quickly achieved as a result of higher T and low RH%





Module configuration:

Glass/glass (G/G) vs glass/backsheet (G/BS) in temperate climate (cool and humid)



- In G/BS, saturation quasi reached at cell back after 1st year, then seasonal variations clearly visible; simulation to be extended for longer period
- G/G reduces moisture accumulation with respect to G/BS (moisture content at cell back already larger in G/BS after 1st year than in G/G after 20 years)

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- Different encapsulants in temperate climate
 - Water concentration in glass/glass (G/G) configuration for 3 encapsulants, simulated for 1 year
- PO#1, a commercial polyolefin-based encapsulant, shows significantly lower moisture ingress than the other 2 EVA encapsulants in one year
- For EVA#1 the water concentration is reduced by over 50% compared to EVA#2
 - EVA formulation plays an important role on water ingress



- These results demonstrate the ability to predict water ingress as a function of:
 - Module configuration
 - Encapsulant
- Care must be taken that not only diffusion coefficient but also solubility are important when choosing the proper material

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Encapsulated capacitance sensor as moisture/T indicator



- The strip is laminated within the encapsulant in two configurations:
 - Encapsulant only
 - Glass/glass and glass/backsheet samples

Results to be presented at the next EU PVSEC (5D010.3)

Then placed in various conditions (climatic chamber and outdoor)

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Comparison of simulated values with outdoor measurements (encapsulated sensors)



- Quite good agreement between measurement and simulation but:
 - Further simulations are required (longer time, controlled conditions)
 - RH value given by the sensor to be directly correlated with amount of water present in the polymer as assesse by an independent method (e.g. Karl Fischer)





- Different encapsulants in extended damp heat
 - Standard solar cells, Glass/Backsheet module configuration, 85 °C / 85% RH, 8000 h.
 - Decrease in power loss corresponds to corrosion of metallic contacts







- Potential Induced Degradation (PID)
 - One of the major failures observed in temperate climate
 - Power degradation due to increased shunt resistance
 - Stress factors: Voltage, Temperature, Humidity → can be mitigated at system but also module level
- Mini-modules prepared with different encapsulant and configuration
 - 2 cells mini-modules, Glass/Glass and Glass/Backsheet
 - Placed in climatic chamber at RH = 85% and T = 40°C/60°C/85°C for 96 hours
 - Leakage current monitored and mini-modules characterized with IV, EL





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First results at RH = 85% are in agreement with literature:



- Impact of encapsulant: almost no degradation for EVA 1 G/G and TPO, EVA 2 worst case
- Tests to be repeated at fixed temperature and various humidity, also with other c-Si based cells

- Leakage current increases with T
 → fit with an Arrhenius law
- Impact of encapsulant: for EVA activation energy ~ 80 kJ/mol (in line with literature), TPO well above







- Moisture ingress has a strong impact on module reliability and lifetime
- A good model exist to simulate the moisture ingress into both G/G and G/BS modules, with which the effect of module configuration and packaging materials can be evaluated
- An in-situ RH/T sensor system embedded into PV modules was developed and applied, to measure the actual RH and T inside the module and was used to validate the model
- Results of outdoor data, water ingress simulations and ATLs provide first bricks to predictive modeling
- This predictive model must consider specificities linked to climate and operating conditions (e.g. integrated roof, façades vs stand-alone) based on reported major failure mechanisms
- The model is first develop for standard c-Si cells then should be extended to advanced c-Si based technologies (PERC, IBC, HJT)





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